

3-Wire Programmable Camkshaft Position Sensor

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1. Features

- AEC-Q100 qualified
- ISO 26262 ASIL-B
- TPO functionality with optinal Auto-TPO adaption in EEPROM
- Customer-side programming enable
- Operation Temperature: -40°C~150°C
- Operation Voltage: 4V~16V
- High Accuracy and High Sensitivity
- 3-pin PCB-less TS-3 package

2. Applications

- Camshaft position detection
- High accuracy gear position detection

3. Description

The SC9388 is produced by Bi-CMOS technology, it's a chopper-stabilized & active differential Hall sensor ideally suited for camshaft phase detection applications. It have the auto-adjust function to keep the performance with high accuracy and low jitter capabilities.

Superior high-temperature performance is made possible through dynamic offset cancellation & internal temperature compensation algorithm, which reduces the residual offset voltage normally caused by device over molding, temperature dependencies, and thermal stress. Each device includes on a single silicon chip a voltage regulator, Hall-voltage generator, small-signal amplifier, chopper stabilization circuits, digital process circuits, EEPROM, diagnostic circuits.

An onboard regulator permits with supply voltages of 4 to 16V which makes the device suitable for a wide range of industrial and automotive applications

The device is available in a 3-pin package (TS-3) Which integrated with capacitor.

It is lead (Pb) free, with 100% matte tin-plated lead frame.



Fig.1 TS-3 Package Outline



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4. Terminal Configuration

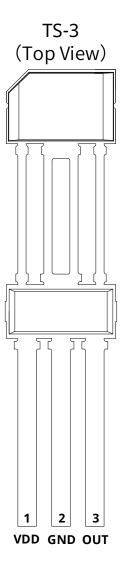


Fig.2 Pin Description

Те	rminal	Tymo	Dogavintian
Name	Number	Туре	Description
VDD	1	PWR	4V~16V power supply
GND	2	Ground	Ground terminal
OUT	3	Output	Open-drain output. The open drain requires a pull-up resistor



5. Ordering Information

Ordering Information	Ordering Information Marking		Package	Packing	Quantity	
SC9388T3-TR-Q	9388	-40 ~ 150	TS-3	Tape & reel	1500 /reel	



6. Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) $^{(1)}\,$

Symbol	Parameter	Test conditions		Max.	Units
V	Dower supply voltage (1)	continuous, T _J ≤170°C	-16	18	٧
V _{DD}	Power supply voltage ⁽¹⁾	max. 60s, T _J ≤170°C	-18	27	V
	Outro 4 Off and to a (1)	continuous, T _J ≤170°C	-0.3	26.5	V
V _{OUT-Off} Output Off voltage (1)		max. 1h, T _{Amh} ≤40°C	-1.0	26.5	V
	V _{OUT-On} Output On voltage ⁽¹⁾	continuous, T _{Amh} ≪40°C	-1.0	16	V
V _{OUT-On}		max. 1h, T _{Amh} ≤40°C	-0.3	18	٧
		max. 60s, T _{Amh} ≤40°C	-0.3	26.5	V
T _A	Operating ambient temperature		-40	150	°C
T _J	Maximum junction temperature	Exposure time: max. 10×1h, V _{DD} =16V	-4	175	°C
R_L	Magnetic field induction ⁽²⁾	Magnetic pulse during magnet magnetization. Valid with T _{ambient} ≤ 80°C	-4	4	Т

Note:

7. ESD Protection

Symbol	Parameter	Test conditions		Max.	Units
V _{ESD}	ESD-Protection	Protection Refer to AEC-Q100-002E HBM standard,R=1.5kΩ, C=100pF		8	kV

8. Thermal Characteristics

Symbol	Parameter	Test conditions		Max.	Units
$R_{ heta JA}$	Package thermal resistance	Without PCB, welding process with lead-frame	-	190	°C/W

⁽¹⁾ tresses above those listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

⁽²⁾ Guaranteed by design.



9. Operating Characteristics

over operating free-air temperature range (V_{DD} =5.0V, unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Electrical pa	arameters					
V_{DD}	Supply Voltage		4	-	16	V
V_{Q_OFF}	Continuous Output Off voltage		1	-	16	V
dV _{DD} /dt	Supply voltage power- up/down voltage ramp		3	-	10000	V/ms
V_{Qsat}	Output saturation voltage	I _Q ≤15mA	-	-	500	mV
V_{DD_clamp}	Clamping voltage V _{DD} -Pin	Leakage current through ESD diode<0.5mA	42	-	-	V
V_{Qclamp}	Clamping voltage V _Q -Pin	leakage current through ESD- diode<0.5mA	42	-	-	V
V_{DD_reset}	Reset voltage		-	-	3.6	٧
I_{DD}	Supply current		8	-	13.4	mA
I_{Q_ON}	Continuous output On current	V _{Q_LOW} <0.5V	0.01	-	15	mA
I_{Qleak}	Output leakage current	V _Q =18V	-	0.1	10	μΑ
I_{Qshort}	Output current limit during short-circuit condition		30	-	80	mA
Time & Freq	uency Related					
t _{power_on}	Power on time	During this time the output is locked to high.	0.8	0.9	1	ms
t _{delay}	Delay time between magnetic signal switching point and corresponding output signal falling edge switching event	Falling edge	10	14	19	μs
t _{delay2}		Option 2	13	17	22	μs
t _{delay3}	Further options on delay time accessible using EEPROM	Option 3	16	20	25	μs
t _{delay4}		Option 4	19	23	28	μs
		V_{Pullup} =5V, R_{Pullup} =1.2k Ω (±10%), C_Q =1.8nF (±15%), valid between 80%-20%	2.0	2.5	3.0	μs
t _{fall}	Output fall time	V_{Pullup} =5V, R_{Pullup} =1.2k Ω (±10%), C_{Q} =1.8nF (±15%), valid between 90%-10%	3.2	4.5	5.8	μs
t _{rise}	Output rise time	R_{Pullup} =1.2k Ω (±10%), C_Q =1.8nF (±15%), valid between 10%-90%	4	-	11.4	μs
N_{PROG}	Maximum No. of EEPROM programming cycles	T _J <150°C	-	-	80	n
f	Magnetic signal frequency range	Full accuracy	0	-	8000	Hz
C_VDD	Capacitance between IC supply & ground pins		90	100	110	nF



Operating Characteristics (continued)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
C _Q	Output capacitance between IC output and ground pins		2.09	2.2	2.31	nF
Magnetic Sig	gnal					
DR _{mag_field_dir}	Dynamic range of the magnetic field of the direction channel		-60	-	60	mT
SR _{mag_field_s_bb}	Static range of the magnetic field of the outer Hall probes in back-bias configuration	No wheel in front of module / Offset-DAC- Compensation-range	0	-	550	mT
Hysteresis O	f Switching Threshold					
Switch_Off set,Error	Switching level offset	For magnetic speed signal =10mT _{pkpk} : resulting in phase error/duty cycle error	-350	-	350	μТ
		EEPROM "K_FACTOR":Option 0000	-	39.1	-	%
		EEPROM "K_FACTOR":Option 0001	-	40.6	-	%
		EEPROM "K_FACTOR":Option 0010	-	42.2	-	%
	Programming switching level offset (k-factor)	EEPROM "K_FACTOR":Option 0011	-	43.8	-	%
		EEPROM "K_FACTOR":Option 0100	-	45.3	-	%
		EEPROM "K_FACTOR":Option 0101	-	46.9	-	%
		EEPROM "K_FACTOR":Option 0110	-	48.4	-	%
K_factor		EEPROM "K_FACTOR":Option 0111	46.3	50.0	53.7	%
K_IdCtOr		EEPROM "K_FACTOR":Option 1000	-	51.6	-	%
		EEPROM "K_FACTOR":Option 1001	-	53.1	-	%
		EEPROM "K_FACTOR":Option 1010	-	54.7	-	%
		EEPROM "K_FACTOR":Option 1011	-	56.3	-	%
		EEPROM "K_FACTOR":Option 1100	-	57.8	-	%
		EEPROM "K_FACTOR":Option 1101	-	59.4	-	%
		EEPROM "K_FACTOR": Option 1110	-	60.9	-	%
		EEPROM "K_FACTOR":Option 1111	-	62.5	-	%



Operating Characteristics (continued)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Accuracy	Related					
		3 sigma, ΔB _{pkpk} =20mT _{pkpk} , FILTER_SELECT=0	-	-	0.015	°Crank
Jitter	Repeatability (Jitter)	3 sigma, ΔB _{pkpk} =9mT _{pkpk} , measured on coil using sinus signal, T _A =150°C, f=8kHz, FILTER_SELECT=0	-	-	0.025	°Crank
Phirunni ng	Maximum phase error	ΔB _{Speed} >9mT _{pkpk} , signature excluded, accuracy on mentioned wheel in Figure 4	-0.2	-	0.2	°Crank
Phistop, start	Maximum phase error after stop-start	Reduced phase accuracy only for first pulse after stop-start-state / signature excluded	-1.7	ı	3.2	°Crank
Tempera	ture Related					
T _J	Normal operating junction temperature	Exposure time: max. 2500h at T_j =175°C, V_{DD} =16V	-40	-	175	°C
		Exposuretime: max. $10 \times 1 h$ at $T_j = 185 \degree C$, $V_{DD} = 16 V$, additive to other lifetime	-40	-	185	°C
T _{no}	Not operational lifetime	Withoutsensorfunction. Exposure time max 500h @ 150°C; increased time for lower temperatures according to Arrhenius-Model, additive to other lifetime	-40	-	150	°C
T_{RDPROG}	Ambient temperature range for customer programming		15	25	130	°C
T _C	Temperature compensation range of magnetic material	Internal compensation of magnetic signal amplitude of speed signal	1900	-	0	ppm



10. Block Diagram

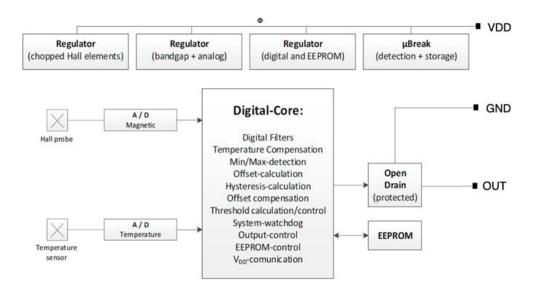


Fig.3 Block Diagram

Contains several circuits:

Chopped Hall Amplifier	Under/Over Voltage Detection
Offset Calibration ADC	POR
PGA + LPF	osc
Channel ADC(Tracking ADC)	EEPROM programmable
Analog & Digital VDD Regulator	EMC Protection
Current Bias	ASIL / Diagnostic



11 Function Description

Working Principle

Speed detection configuration of SC9388 is illustrated in below Figure. It contains a toothed wheel or magnetic encoder on a rotating shaft, the speed-sensor itself where connecting cables are attached and the back-bias magnet or magnetic encoder which generates a static field on the position of the sensing elements (Hall probes). The movement of the target wheel modulates the flux-lines of the magnetic field. This modulation is measured as camshaft phase signal which is output on the open drain mode.

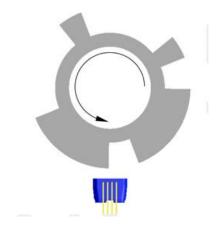


Fig.4 Detection Principle

Operation Temperature

Ambient temperature: -40°C ~ 150°C

Peak temperature: 150°C during 3h

Frequency (peak temperature): 160 times during lifetime

Nominal temperature: T= 80°C ~ 110°C

Temperature Profile:

Temperature(℃)	-40	-20	25	80	100	110	125	150
Vehicle lifetime (%)	0.03	0.67	1.5	27	43.89	23	3.5	0.41

Operation Steps

The basic operation of this sensor is to transpose the magnetic field produced by a spinning target wheel into phase information at the output pin. The output voltage indicates forward a teeth or valley and can be adjusted in EEPROM-options.

The correspondence between field polarity and output polarity can be set according to the application needs.

By definition a magnetic field is considered as positive if the magnetic North Pole is placed at the rear side of the sensor.



The operation need to be split to five different phases:

- Power-on phase
- starts after supply release;
- Lasts tpower-on (power-on time);
- IC loads configuration and settings from EEPROM and initializes state machines and signal path;
- Initial phase
- starts after Power-on phase;
- lasts one clock cycle;
- IC enables output switching, extrema detection and threshold adaption;
- Calibration phase
- starts after Initial phase
- Running phase
- starts after "Calibration Phase";
- after a programmable number of switching events (2 to 128) the accuracy is considered to be quite high. At this time the chip is switched into a calibrated phase(running phase) where only minor threshold corrections are allowed.

Averaging Algorithm

To calculate the threshold within the running phase, valid maxima and minima are averaged to reduce possible offset-updates. Each offset-update gives an increased jitter, which has to be avoided.

The algorithm can be able to choose different number of teeth for averaging.

And the algorithm can be set to: Once the feature signal is captured, the offset calibration value can be updated to previous round result.

Hysteresis Concept

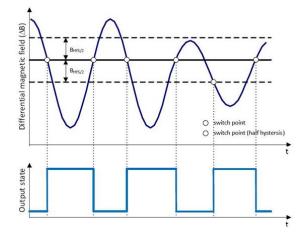


Fig.5 Hysteresis definition



The prefered switching behavior for camshaft application in terms of hysteresis is called hidden adaptive hysteresis. For reason of long notches or long teeth there is the EEPROM possibility to go for visible hysteresis as well. Another EEPROM possibility is fixed hysteresis, which allows robustness against metalic flakes attached by the back-bias-magnet.

Hidden adaptive hysteresis means, the output always switches at the same level, centered between upper and lower hysteresis. These hysteresis thresholds needs to be exceeded and are used to enable the output for the next following switching event. For example, if the differential magnetic field crosses the lower hysteresis level, then the output is able to switch at the zero crossing. Next following upper hysteresis needs to be exceeded again in order to enable for the next switching. Furthermore, the function of half hysteresis maintains switching whenever the upper hysteresis level is not exceeded, but the lower hysteresis level is crossed again, then the output is allowed to switch, so that no edge is lost. However, this causes additional phase error, see Figure 9.

Doing an adaptive hysteresis gives advantage at small airgap (large signal) to have big hysteresis. Compared with fixed hysteresis a small vibration cannot cause additional switching. According 10 adaptive hysteresis is calculated as 25% of the differential Speed-signal peak to peak. The minimum hysteresis is derived from EEPROM setting.

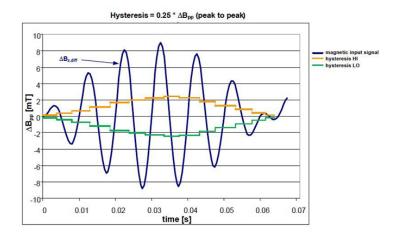


Fig.6 Adaptive Hysteresis

Adjust the proper k-factor

Due to position tolerances of the sensor and of the magnet (X – displacement) the middle of the sensor is not always the middle of the module. And even if the sensor and the module would have the mechanical middle and the magnet is displaced there would be a deviation of the magnetic middle to the module middle.

These tolerances cause a wrong camshaft position sensed and calculated in the engine control unit. Translated to magnetic parameters the teeth are modulating the back bias magnet field lines. The sensor detects the modulation of these field lines.

As all components have their own magnetic and mechanical tolerances, an overall tolerance of something like +/-0.3°crank is the accuracy of the sensed camshaft position. With the introduction of adjustable switching threshold (k-factor) the accuracy of each module can be increased to +/-0.1°crank.

To offer better accuracy, several settings between 39% and 63% should be possible to program. The factor is known as k-factor.

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The calculation of the adaptive programmable switching threshold is done as following: Switching Threshold = Bmin + (Bmax - Bmin) * k.

• Temperature compensation

This sensor should have a constant temperature-measurement of the sensor itself and compensates the difference in the amplitude already in the analog signal path. So themain-comparator as well as the digital core can always see the same amplitude of the signal, independent from temperature of the magnet circuit.



12. Typical Application

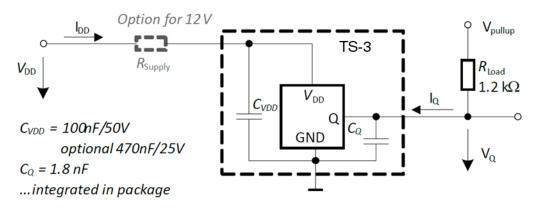


Fig.7 Typical Application Circuit

13. Package Information "TS-3"

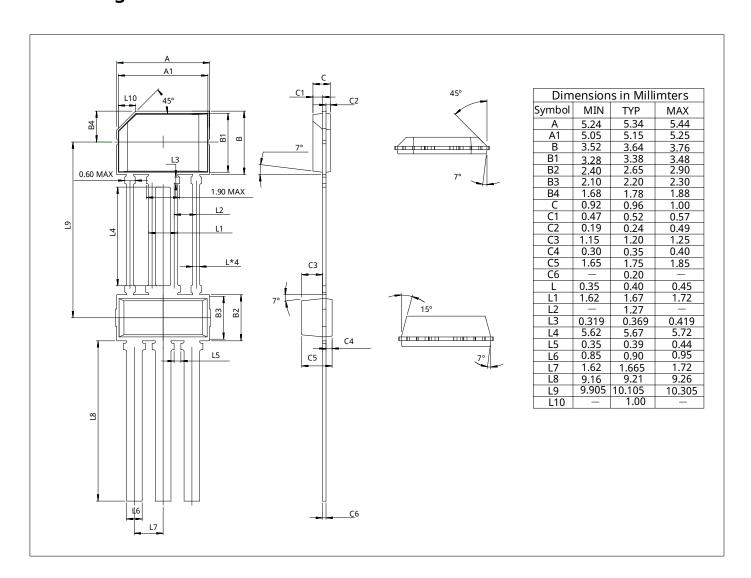


Fig.8 Package Dimension



14. Packing Information

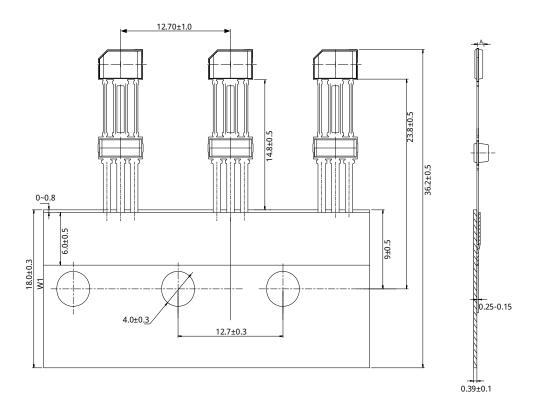


Fig.9 Packing Dimension



14. Revision History

Revision	Date	Description
Rev0.1	2024-03-20	Draft Version
Rev0.2	2025-06-11	Format Updates,Preliminary Version